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## Communication

Electrospun  $\text{Sb}_2\text{Se}_3@\text{C}$  nanofibers with excellent lithium storage propertiesYan Dong<sup>a</sup>, Yuezhan Feng<sup>b,\*</sup>, Jiwei Deng<sup>c,\*</sup>, Pengbin He<sup>a</sup>, Jianmin Ma<sup>a,\*</sup><sup>a</sup> School of Physics and Electronics, Hunan University, Changsha 410082, China<sup>b</sup> Key Laboratory of Materials Processing and Mold (Zhengzhou University), Ministry of Education, Zhengzhou University, Zhengzhou 450002, China<sup>c</sup> College of Mechanical and Electrical Engineering, Central South University, Changsha 410083, China

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## ABSTRACT

Antimony-based materials have become promising anodes within lithium-ion batteries (LIBs) due to their low cost and the high theoretical capacity. However, there is a potential to further enhance the electrochemical performance of such antimony-based materials. Herein,  $\text{Sb}_2\text{Se}_3@\text{C}$  nanofibers ( $\text{Sb}_2\text{Se}_3@\text{CNFs}$ ) are designed and obtained via a novel electrospinning method. Upon electrochemically testing as an anode within LIBs, the  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  (annealed at 600 °C) delivers a remarkably good cycling performance of 625 mAh/g at 100 mA/g after 100 cycles. Moreover, it still remains at 490 mAh/g after 500 cycles with an applied current density of 1.0 A/g. The excellent performance of the  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  can be attributed to the fact that the N-doped C matrices not only remit the volume expansion of materials, but also enhance the electrical and ionic conductivity thusly increasing the lithium-ion diffusion. The obtained  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  are promising anode for LIBs in the future.

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Lithium-ion batteries (LIBs) have been regarded as one of the most promising power sources in energy conversion and storage, due to their long cycle life and high energy density [1,2]. However, the most widely used anode material, graphite, only possesses a limited capacity of 372 mAh/g [3,4], which will not satisfy the requirements needed to power and develop next-generation electronic devices. Hence, it is one of the main challenges to design anode materials with high capacity, long cycling performance and offer a suitable voltage platform [5,6].

To date, many materials such as carbon, metals, oxides, chalcogenides have been used as potential anode materials for LIBs [7–10]. Many nanomaterials have also attracted more attention due to their great mechanical, electrical properties and synergistic effects [11–15]. Among these materials, the metallic antimony (Sb) and Sb-based materials (oxides, chalcogenides and alloys) are of particular focus with the literature [16–20]. Prikhodchenko and co-workers designed an antimony sulfide coated reduced graphene oxide (rGO) that exceeded 720 mAh/g after 50 cycles at a current density of 250 mA/g [21]. Additionally, Park's group fabricated SnSb-CNT nanocomposite by reductive precipitation of metal chloride salts within a CNT suspension,

which possessed a reversible capacity of 480 mAh/g after 50 cycles of the LIBs [22]. As one of the typical group V–VI compounds, antimony selenide ( $\text{Sb}_2\text{Se}_3$ ) is a p-type semiconductor with direct band-gap, and has widely been applied within optics, thermoelectric, electrochemical energy storage to name a few [23–25]. Regarding anode material for LIBs, 1 mol  $\text{Sb}_2\text{Se}_3$  could accommodate 12 mol  $\text{Li}^+$  during the lithiation/delithiation reaction, exhibiting a theoretical specific capacity of 670 mAh/g for LIBs. However,  $\text{Sb}_2\text{Se}_3$  suffers some significant hindrances, such as aggregation, pulverization, loss of electrical contact due to the dramatic volume expansion during the lithiation/delithiation process. To solve the aforementioned problems, introduction of a carbon matrix allows for the  $\text{Sb}_2\text{Se}_3$  to offer good performance, which can not only release the stress induced by the volume expansion of materials, but also alleviate agglomeration [26]. Although these promising results have already been obtained, further improvement can still be exhibited within the electrochemical performance.

In this work, we have reported  $\text{Sb}_2\text{Se}_3@\text{C}$  nanofibers ( $\text{Sb}_2\text{Se}_3@\text{CNFs}$ ), synthesized by electrospinning method, as an anode for LIBs. One-dimensional (1D) nanofibers offer the advantage of continuous ion/electron channels, short diffusion distance and better contact between materials and current collectors, leading to an improved rate performance [27]. Additionally, these carbon nanofibers can prevent the huge volume changes during charge/discharge process as they provide a buffer layer, which enhances their overall cycling life [26]. Furthermore,

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the annealing temperatures were also optimized. Hence, when used as the anode for LIBs, the  $\text{Sb}_2\text{Se}_3\text{@CNF}$  annealed at  $600^\circ\text{C}$  ( $\text{Sb}_2\text{Se}_3\text{@CNF-600}$ ) could deliver remarkably high reversible capacities of  $625\text{mAh/g}$  at  $100\text{mA/g}$  after 100 cycles and  $437\text{mAh/g}$  at a large current density of  $1.0\text{A/g}$  after 500 cycles.

The synthesis process of the  $\text{Sb}_2\text{Se}_3\text{@CNFs}$  is as follows:  $0.4936\text{g}$  sodium antimonite ( $\text{NaSbO}_3\cdot 3\text{H}_2\text{O}$ , Tianjin Heowns Biochemical Technology Co., Ltd., China) and  $0.45\text{g}$  polyacrylonitrile (PAN,  $M_w = 150,000$ , Sigma-Aldrich Co., Ltd., USA) were dissolved in  $4.5\text{g}$   $N,N$ -dimethylformamide (DMF) solvent at room temperature with vigorous stirring for 2 h. Then,  $0.3948\text{g}$  Se powder (Aladdin Industrial Corporation, Ltd., USA) was added into the solution and kept vigorous stirring for 12 h. The as-prepared precursor solution was transferred into a 10-mL syringe connected to a stainless steel needle. A high voltage power supply was used to provide a  $12\text{kV}$  high voltage for the resulting precursor. The distance was about  $12\text{cm}$  between the needle and the collector, and the feed speed rate was set up at  $0.4\text{mL/h}$ . After that, the prepared nanofibers were dried at  $60^\circ\text{C}$  for 12 h in vacuum oven. Afterward, the fibers were annealed in a tube furnace under Ar atmosphere at  $500^\circ\text{C}$ ,  $600^\circ\text{C}$ ,  $700^\circ\text{C}$  for 2 h with a heating rate of  $3^\circ\text{C/min}$ , respectively. These samples were marked as  $\text{Sb}_2\text{Se}_3\text{@CNF-500}$ ,  $\text{Sb}_2\text{Se}_3\text{@CNF-600}$  and  $\text{Sb}_2\text{Se}_3\text{@CNF-700}$ , respectively. The produced nanofibers were washed by distilled water and ethanol for several times after dipping in the acetic acid solution for 24 h. Finally, the  $\text{Sb}_2\text{Se}_3\text{@CNFs}$  were collected after drying overnight in the air. And the N-doped C nanofibers (NCNFs) were prepared according the same process except without sodium antimonite and selenium powder.

The X-ray diffraction (XRD, Rigaku D/MAX-2500) was utilized to determine the phase composition and purity of the as-prepared composites. The morphology and structure of  $\text{Sb}_2\text{Se}_3\text{@CNFs}$  were analyzed by scanning electron microscopy (SEM, Hitachi S4800) and transmission electron microscopy (TEM, JEOL 2010). To confirm  $\text{Sb}_2\text{Se}_3$  content in the samples, the thermogravimetric analysis (TGA, Setaram O18124) of the samples was carried out in air atmosphere from  $30^\circ\text{C}$  to  $800^\circ\text{C}$  with a heating rate of  $10^\circ\text{C/min}$ . The surface area and pore width distribution of the sample were performed by Brunauer–Emmett–Teller (BET, Micromeritics ASAP 2460) with the adsorption of  $\text{N}_2$ . X-ray

photoelectron spectroscopy (XPS, Thermo Scientific Escalab 250Xi, USA) was used to research the element composition and chemical bonds of the samples.

Electrochemical performance was investigated by using CR-2025 coin-type cells. The tested coin cells were assembled in a pure argon gas glove box with the contents of  $\text{H}_2\text{O}$  and  $\text{O}_2$  less than  $0.5\text{ppm}$ . And the working electrodes were prepared as following: Active material (80 wt%), acetylene carbon black (10 wt%) and carboxymethyl cellulose (CMC, 10 wt%) were mixed together and dispersed in a mixed solvent of ethanol and distilled water, in order to form a uniform slurry. Subsequently, the mixed slurry was coated on copper foil and dried at  $60^\circ\text{C}$  for 24 h. Generally, the average active material mass loading was controlled about  $1.0\text{mg/cm}^2$ . The counter electrode was Li metal. The electrolyte was  $1.0\text{mol/L}$   $\text{LiPF}_6$  dissolving in a 1:1 volumetric mixture of ethylene carbonate (EC) and dimethyl carbonate (DMC). Galvanostatic charge–discharge testing was carried on a Neware battery testing system in a voltage window of  $0.01\text{--}3\text{V}$ . Cyclic voltammetry measurements (CV) and electrochemical impedance spectroscopy (EIS) were performed by using a CHI 660e electrochemical workstation.

The crystal structures of  $\text{Sb}_2\text{Se}_3\text{@CNFs}$  annealed at the different temperatures were characterized by XRD (Fig. 1a). It is obvious that all diffraction peaks of  $\text{Sb}_2\text{Se}_3\text{@CNF-600}$  correspond well to the orthorhombic  $\text{Sb}_2\text{Se}_3$  phase with the space group Pbnm (JCPDS No.15-0086) [18,28]. The  $2\theta$  values of the main peaks are located at  $15.02^\circ$ ,  $16.88^\circ$ ,  $23.9^\circ$ ,  $27.38^\circ$ ,  $28.20^\circ$ ,  $31.16^\circ$ ,  $32.22^\circ$ ,  $33.10^\circ$ ,  $34.06^\circ$ ,  $35.68^\circ$ ,  $38.8^\circ$ ,  $41.3^\circ$ ,  $45.06^\circ$  and  $51.88^\circ$  which corresponded to the (020), (120), (130), (221), (301), (311), (240), (321), (141), (250), (501) and (061) lattice planes of orthorhombic  $\text{Sb}_2\text{Se}_3$ , respectively. On the contrary,  $\text{Sb}_2\text{Se}_3\text{@CNF-500}$  possesses other crystal phases. Among them, the diffraction peaks at  $29.74^\circ$ ,  $43.64^\circ$  are associated with the (101), (102) lattice planes of Se (JCPDS No. 06-0362). Such lattice planes could be due to the separation of the reactants during the electrospinning process, and thus do not react well at  $500^\circ\text{C}$ , resulting in the existence of Se. The  $\text{Sb}_2\text{Se}_3\text{@CNF-700}$  has no obvious diffraction peak for  $\text{Sb}_2\text{Se}_3$ , but only possesses a broad carbon peak (JCPDS No. 03-0401). This might be ascribed to the least  $\text{Sb}_2\text{Se}_3$  content of  $\text{Sb}_2\text{Se}_3\text{@CNF-700}$ . And the crystallite size of  $\text{Sb}_2\text{Se}_3$  can be calculated with the Scherrer equation of  $D =$

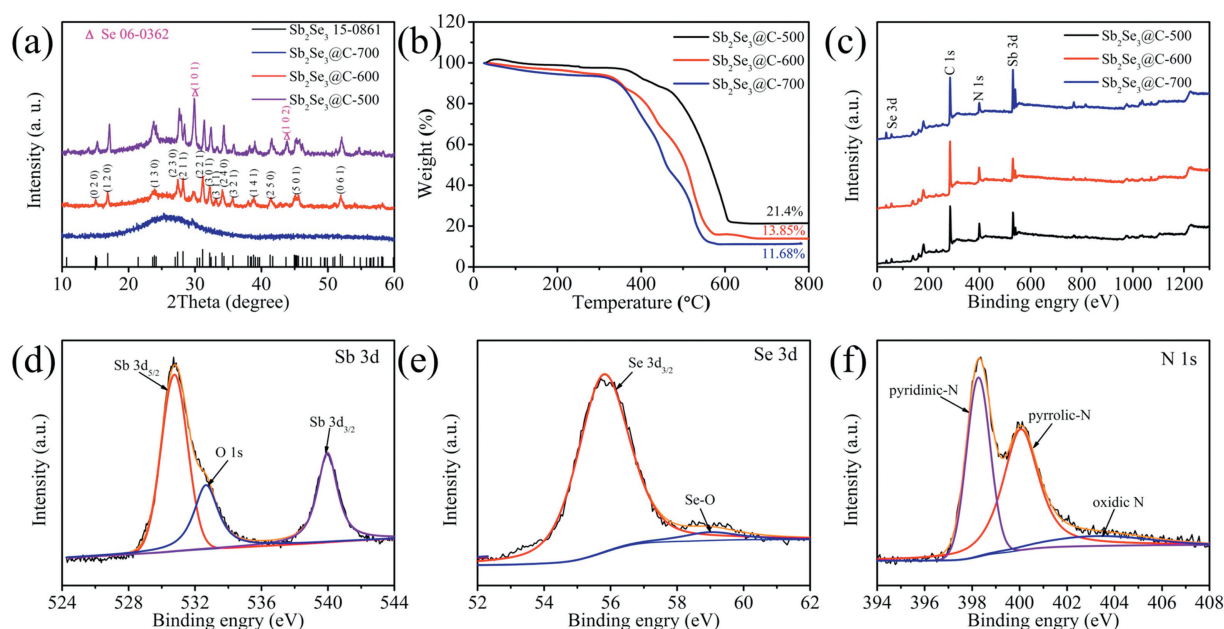


Fig. 1. (a) XRD patterns, (b) TGA curves, (c) XPS spectra of all elements of  $\text{Sb}_2\text{Se}_3\text{@CNF}$ , (d) Sb 3d, (e) Se 3d and (f) N 1s of  $\text{Sb}_2\text{Se}_3\text{@CNF-600}$ .

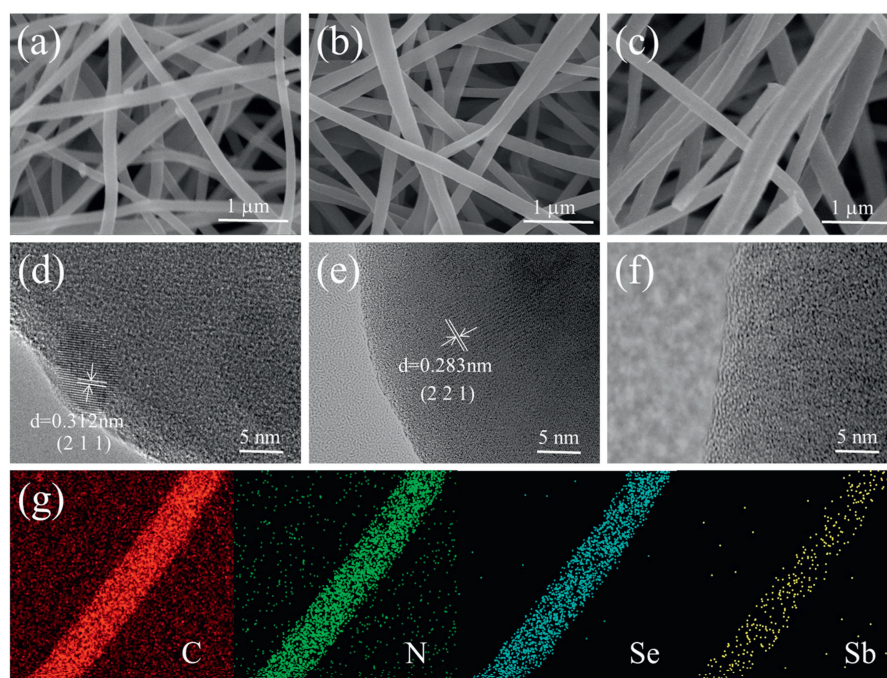
$k\lambda/(\beta\cos\theta)$ , where  $\theta$  is the Bragg angle in degrees;  $D$  is the size of crystallites;  $k$  is the shape factor of 0.89;  $\lambda$  is the X-ray wavelength of 1.54 Å and  $\beta$  is the fwhm of the reflection peaks [29]. The calculated average crystallite sizes are 26.81 and 22.08 nm for  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$  and  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ , respectively. The grain size is one of the important factors for lithium storage: the smaller the particle size benefits the mobility of Li ions [30]. Hence, the grain size of  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$  is better than  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$ .

The  $\text{Sb}_2\text{Se}_3$  contents in  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  were carried out by TGA (Fig. 1b). The gradual decrease at the start of the curves (*i.e.*, below 200 °C) can be observed, due to the evaporation of water [31]. Upon the oxidation of  $\text{Sb}_2\text{Se}_3$  to  $\text{Sb}_2\text{O}_4$  and formation of  $\text{SeO}_2$  and  $\text{CO}_2$ , the weights of the  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  rapidly decreased over the temperature range of 350–600 °C. The oxidation reaction is:  $\text{Sb}_2\text{Se}_3 + 5\text{O}_2 = \text{Sb}_2\text{O}_4 + 3\text{SeO}_2\uparrow$  [7,28]. From the result of TGA, the  $\text{Sb}_2\text{Se}_3$  content of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500/600/700$  can be calculated as 33.43%, 21.64% and 18.24%, respectively. It is clear that the  $\text{Sb}_2\text{Se}_3$  content of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500/600/700$  became less with the higher annealing temperatures.

To obtain the information about the elemental valences and compositions, the as-prepared products were characterized further by XPS, and results are depicted in Figs. 1c–f and Fig. S1 (Supporting information). The whole XPS spectra (Fig. 1c) reveals the existence of Sb, Se, C and N elements in all the samples tested. The high-resolution peaks of the Sb 3d in Fig. 1d can be divided into three significant peaks of 530.76 eV, 532.66 eV and 539.96 eV, respectively. Moreover, the peaks of 530.76 eV and 539.96 eV correspond to Sb 3d<sub>5/2</sub> and Sb 3d<sub>3/2</sub>, respectively, indicating the presence of Sb<sup>3+</sup> in the  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ . It should be noted that the peak of 532.66 eV is present due to a small amount of surface oxidation of the  $\text{Sb}_2\text{Se}_3$ , relating to the O 1s [31,32]. Presented in Fig. 1e, are peaks positioned at 55.79 eV and 58.98 eV that are related to Se 3d<sub>3/2</sub> and Se–O bond, meaning the presence of Se<sup>2–</sup> in the  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$  nanofibers is evident [32,33]. The high-resolution peaks of Sb 3d and Se 3d of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$  and  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$  were displayed in Figs. S1a–e, exhibiting similar spectra to the  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ . Furthermore, the peaks of the C 1s

in the  $\text{Sb}_2\text{Se}_3@\text{C}-500$ ,  $\text{Sb}_2\text{Se}_3@\text{C}-600$  and  $\text{Sb}_2\text{Se}_3@\text{C}-700$  could be resolved into three binding energies, shown in Figs. S1g–i. The peak located at 284.77 eV, 286.36 eV and 288.88 eV correspond to the C–C, C–O and C=O bond, respectively [7,34]. In addition, the high-resolution N 1s spectra of  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$  in Fig. 1f can be attributed to pyridinic-N, pyrrolic-N and oxidic-N, which appears at ~398.26 eV, 400.05 eV and 403.23 eV, respectively. While the N 1s spectra of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$  and  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$  are demonstrated in Figs. S1c and f, with the relative content of each nitrogen type being shown in Table S1 (Supporting information). It is proved that N-doped carbon materials have a higher capacity. First, because the doped N can offer more electrons to the  $\pi$ -conjugated system of carbon, enhance the electronic properties of neighboring carbon atoms, then strengthen the electronic conductivity of carbon nanofibers [35]. Secondly, the electronegativity of nitrogen is higher than carbon and then produces more binding sites for Li ions [36]. And that the carbon atoms around the nitrogen atoms have become more electronegative to adsorb more Li ions in these areas. On the other hand, pyridinic-N and pyrrolic-N create more open channels and defects in carbon due to N substitution for more Li<sup>+</sup> insertion [37–39]. The high content of pyridinic-N and pyrrolic-N will therefore benefit the Li<sup>+</sup> storage properties of the  $\text{Sb}_2\text{Se}_3@\text{CNF}$ . The overall content of pyridinic-N and pyrrolic-N within the  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$  is the highest, which can help Li<sup>+</sup> storage in sample. Similarly, with the results of XRD and TGA, the characterization of XPS also indicates that 600 °C is the most appropriate annealing temperature.

The morphologies of the as-obtained  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$  and CNFs were characterized by SEM, TEM and HR-TEM (Figs. 2a–f, Figs. S2 and S3 in Supporting information), respectively. The SEM images of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$  and  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$  in Figs. 2a–c reveal the nanofiber-like morphology that displays individual and uniform nanofibers with a diameter of ~150–200 nm, which is also confirmed by the TEM images (Figs. S2d–f). As exhibited in the HR-TEM images (Figs. 2d–f), there are lattice fringes with distances of 0.312 nm and 0.283 nm for the  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$  and  $\text{Sb}_2\text{Se}_3@\text{CNF}-$



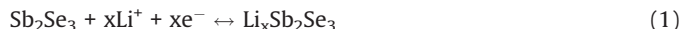
**Fig. 2.** (a–c) SEM images of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ , and  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$ ; (d–f) HR-TEM images of  $\text{Sb}_2\text{Se}_3@\text{CNF}-500$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ , and  $\text{Sb}_2\text{Se}_3@\text{CNF}-700$ ; (g) EDS spectra of  $\text{Sb}_2\text{Se}_3@\text{CNF}-600$ .

600 corresponding to the (2 1 1) plane and (2 2 1) plane of orthorhombic  $\text{Sb}_2\text{Se}_3$  (JCPDS No. 15-0086), indicating that  $\text{Sb}_2\text{Se}_3$  exists within the carbon nanofibers. The electron diffraction X-ray spectroscopy (EDS) spectra of  $\text{Sb}_2\text{Se}_3$ @CNF-600 in Fig. 2g demonstrate the C, N, Se, Sb elements distribution within the nanofibers. The flexible matrix consisting of 1D nanofibers offers the advantages of continuous ion/electron channels and short diffusion distances, and also prevents the huge volume changes during charge/discharge process acting as a buffering layer [27,40]. Thus, the structure of  $\text{Sb}_2\text{Se}_3$ @CNFs will facilitate them to enhance both the rate performance and cycling life.

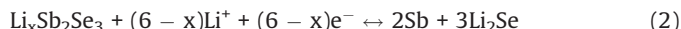
BET analysis was carried out to study the specific surface area of the  $\text{Sb}_2\text{Se}_3$ @CNFs. Fig. 3 and Table S2 (Supporting information) show the nitrogen adsorption–desorption isotherms, pore width and specific surface area of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700, which are about 4.62  $\text{m}^2/\text{g}$ , 6.07  $\text{m}^2/\text{g}$  and 7.58  $\text{m}^2/\text{g}$ , respectively. The more irreversible solid electrolyte interphase (SEI) is formed due to the larger specific surface area. In addition to this, higher pore width can lead to a higher irreversible Li storage and then present poor cycling performance [41]. The suitable specific surface area can make  $\text{Sb}_2\text{Se}_3$ @CNFs exhibit excellent performance for LIBs.

The electrochemical performances of the  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 as anode materials for LIBs were next investigated. The initial three cyclic voltammograms (CV) of the  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 over the voltage range of 0.001 V to 3.0 V (at a scan rate of 0.1 mV/s) are depicted in Figs. 4a–c. Upon the first cathodic scan (Fig. 4b), three peaks  $\text{Sb}_2\text{Se}_3$ @CNF-600 positioned at 1.37, 1.05 and 0.58 V are observed. The reduction peaks at 1.37 and 1.05 V could correspond to the  $\text{Li}^+$  intercalation into the  $\text{Sb}_2\text{Se}_3$  host, to form  $\text{Li}_x\text{Sb}_2\text{Se}_3$  and the formation of Sb nanoparticles embedded within the  $\text{Li}_2\text{Se}$ , respectively. The peak located at 0.58 V is associated with the alloying reaction between Sb and  $\text{Li}^+$  [42]. Additionally, upon the first anode scan, three oxidation peaks of 1.06, 1.86 and 2.06 V are observed. The distinctive peak at 1.06 V corresponds to the  $\text{Li}_3\text{Sb}$  dealloying reaction, leading to the formation of Sb. Due to the conversion reaction between  $\text{Li}_2\text{Se}$  and Sb, in order to form  $\text{Li}_x\text{Sb}_2\text{Se}_3$ , the small peak about 1.86 V was present. While the peak at 2.06 V is associated with the delithiation reaction of  $\text{Li}_x\text{Sb}_2\text{Se}_3$  and formation of  $\text{Sb}_2\text{Se}_3$  [31]. In the following two cycles, the reduction peaks at about 1.9, 1.41 and 0.6 V were associated with the  $\text{Li}^+$  intercalation reaction, the reversible conversion reaction of  $\text{Sb}_2\text{Se}_3$  and alloying reaction between Sb and  $\text{Li}^+$ . They are different from the value of the first cycle, due to formation of the solid electrolyte interphase (SEI) film upon the first cycle. While the oxidation peaks in the subsequent two cycles are similar to that in the first cycle, presented at 1.05, 1.83 and 2.1 V. Meaning that the took place of dealloying reaction between Sb and  $\text{Li}^+$ , the conversion reaction and  $\text{Li}^+$  deintercalation reaction. The electrochemical reactions between  $\text{Sb}_2\text{Se}_3$ @CNF and lithium can be expressed as follows:

Intercalation/deintercalation:



Conversion reaction:



Alloying/dealloying reaction:



The charge/discharge profiles of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 for the 1<sup>st</sup>, 2<sup>nd</sup>, 3<sup>rd</sup> and 5<sup>th</sup> cycle at a current density of 100 mA/g are displayed at in Figs. 4d–f. The charge–discharge voltage platforms of  $\text{Sb}_2\text{Se}_3$ @CNF can be consistent with the redox peaks of above CV curves. The first cycle of discharge plateaus at 1.38 V is related to the  $\text{Li}^+$  intercalation and 1.18 V is associated with conversion reaction of  $\text{Sb}_2\text{Se}_3$ . Moreover, the plateau at 0.87 V demonstrates the Li–Sb alloying process. The initial discharge–charge capacities of the  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 are 1087.30/845.24, 952.32/724.21 and 783.02/589.62 mAh/g, respectively. Furthermore, the initial coulombic efficiency (CE) is 77.74%, 76.04% and 75.3%, respectively. The low CE may be resulted from the formation of SEI film and the irreversible reactions of electrode in the first cycle [19,43]. According to BET analysis, specific surface area of  $\text{Sb}_2\text{Se}_3$ @CNF-700 is 7.58  $\text{m}^2/\text{g}$ , which is the largest in three samples. If the specific surface area is larger, the more solid electrolyte interphase (SEI) which is irreversible will form. So the initial coulombic efficiency (CE) of  $\text{Sb}_2\text{Se}_3$ @CNF-700 is lowest.

The cycling performance of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 were shown in Fig. 5a. The discharge capacity of  $\text{Sb}_2\text{Se}_3$ @CNF-600 is ~625 mAh/g at a current density of 100 mA/g after 100 cycles, while the discharge capacities of  $\text{Sb}_2\text{Se}_3$ @CNF-500 and  $\text{Sb}_2\text{Se}_3$ @CNF-700 only remain 580 and 506 mAh/g, respectively. From the result of TGA, the  $\text{Sb}_2\text{Se}_3$  content of  $\text{Sb}_2\text{Se}_3$ @CNF-600 can be calculated as 21.64%, and the carbon content is 78.36%. It is reported that the theoretical capacity of graphite and  $\text{Sb}_2\text{Se}_3$  is 372 and 670 mAh/g. Hence, the theoretical capacity of  $\text{Sb}_2\text{Se}_3$ @CNF-600 based on the TGA results is calculated as 436.4 mAh/g. The 1D N-doped carbon nanofibers can interlink into a 3D conductive network, it not only enhances the electrons and  $\text{Li}^+$  ions diffusion kinetics, but also weakens the large volume fluctuation of  $\text{Sb}_2\text{Se}_3$ . So  $\text{Sb}_2\text{Se}_3$ @CNF-600 has the higher capacity than theoretical capacity. Fig. 5b and Fig. S4b (Supporting information) demonstrates the rate performance of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600,  $\text{Sb}_2\text{Se}_3$ @CNF-700 and NCNFs, respectively. The average capacities of the  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600,  $\text{Sb}_2\text{Se}_3$ @CNF-700 and NCNFs, are ~613/645/533/572, 560/638/492/429, 488/546/438/288, 460/520/420/320, 440/487/400/314 and 400/437/376/279 mAh/g at varying current densities of 0.1, 0.2, 0.5, 0.8, 1 and 2 A/g, respectively. When the current density returned to 100 mA/g, the discharge capacity of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600,  $\text{Sb}_2\text{Se}_3$ @CNF-700 and NCNFs

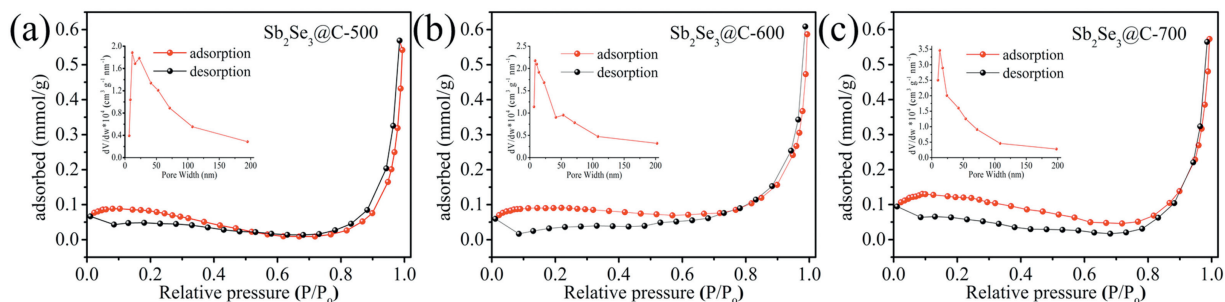
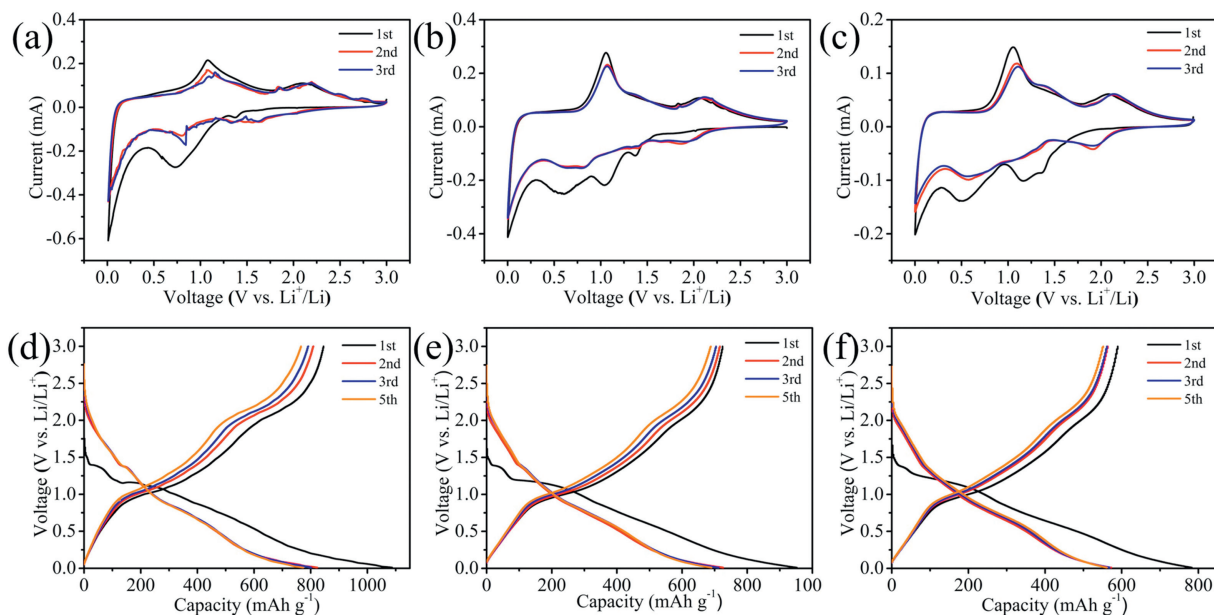
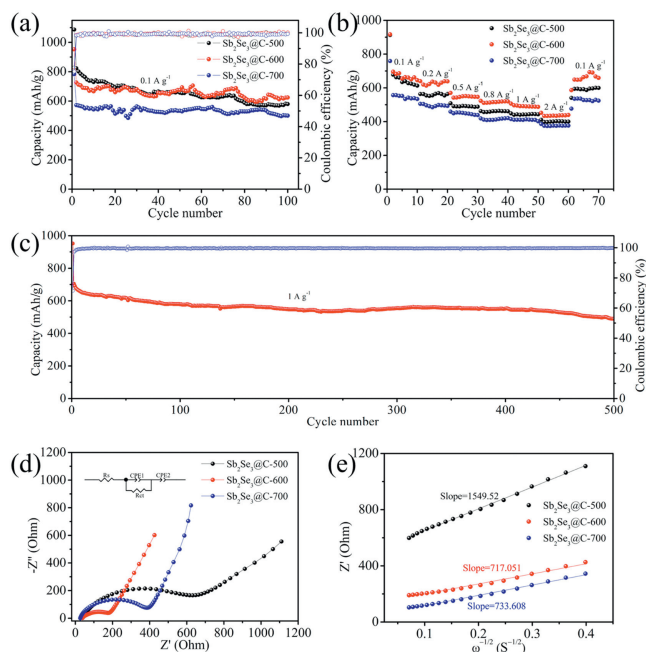


Fig. 3. (a–c)  $\text{N}_2$  adsorption–desorption isotherm of  $\text{Sb}_2\text{Se}_3$ @CNF-500,  $\text{Sb}_2\text{Se}_3$ @CNF-600,  $\text{Sb}_2\text{Se}_3$ @CNF-700, respectively. The inset is the pore width of corresponding samples.



**Fig. 4.** (a–c) Cyclic voltammograms of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  and  $\text{Sb}_2\text{Se}_3@\text{CNF-700}$  at a scan rate of 0.1 mV/s at 100 mA/g; (d–f) Discharge-charge profiles of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  and  $\text{Sb}_2\text{Se}_3@\text{CNF-700}$  during first 3 cycles in a potential window of 0.01–3 V at a current density of 100 mA/g.



**Fig. 5.** (a) Cycling performances and (b) Rate capabilities of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  and  $\text{Sb}_2\text{Se}_3@\text{CNF-700}$ ; (c) Cycling performances of  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  at 1 A/g; (d) Nyquist plots (inset: equivalent circuit model of  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  electrodes) and (e) Relation of  $Z'$  vs.  $\omega^{-1/2}$  in the low frequency region of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}$ ,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  and  $\text{Sb}_2\text{Se}_3@\text{CNF-700}$ .

increased back to 600, 657, 524 and 463 mAh/g, respectively. These results indicate that the  $\text{Sb}_2\text{Se}_3@\text{CNFs}$  possesses good capacity retention upon increasing current density. However, beyond that,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  demonstrates an increased rate performance than the other annealing temperatures due to the high content of pyridinic-N and pyrrolic-N within the carbon matrix. Fig. 5c demonstrates that the  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  exhibits a good long-term cycling performance, needed for futuristic electronic devices. When the current density was set to 1 A/g, the discharge capacity remained at 490 mAh/g after 500 cycles and the coulombic

efficiency reached at 100%. While in Fig. S4c (Supporting information), NCFNs only remains at 386 mAh/g after 350 cycles with an applied current density of 1.0 A/g. From the SEM images (Fig. S5 in Supporting information) of the  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  electrode after cycling, we can observe the obvious carbon fibers could be retained after cycling. It demonstrates that the  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  electrodes have the better cycle performance and rate capability due to N-doped carbon nanofibers which can resist the huge volume changes. In addition to above results, compared with other  $\text{Sb}_2\text{Se}_3$  and  $\text{Sb}_2\text{Se}_3/\text{C}$  composites using different synthetic methods (Table S3 in Supporting information) [18,31,42,44–48], it is obvious that the  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  have long cycling stability and remarkable rate performance when applied as a material within LIBs.

To further understand the resistance and charge transfer properties of the  $\text{Sb}_2\text{Se}_3@\text{CNF}$  electrodes, EIS measurements were carried out. The Nyquist plot reveals a depressed semicircle in the state of high frequency that is attributed to the impedance of SEI film and charge transfer resistance on the electrode/electrolyte interface, while the inclined line in low-frequency regions was related to the diffusion of  $\text{Li}^+$  within the materials [49]. As depicted in Fig. 5d,  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  has a charge transfer resistance ( $R_{ct}$ ) of 151  $\Omega$ , which is much smaller than that of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}$  (540.4  $\Omega$ ) and  $\text{Sb}_2\text{Se}_3@\text{CNF-700}$  (358.3  $\Omega$ ) electrode. The smaller  $R_{ct}$  benefits the higher rate capability, which proves the excellent rate performance of  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$ . The relationships between  $Z'$  with  $\omega^{-1/2}$  ( $\omega = 2\pi f$ ) in Fig. 5e shows that the slope of  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  is the smallest than others. And the diffusion coefficients of  $\text{Li}^+$  in all electrodes can be calculated by the equation:  $D = 0.5R^2T^2/S^2n^4F^4C^2\sigma^2$  [50]. Hence, the  $\text{Li}^+$  diffusion coefficients of  $\text{Sb}_2\text{Se}_3@\text{CNF-500}/600/700$  are calculated to be  $0.40 \times 10^{-16}$   $\text{cm}^2/\text{s}$ ,  $1.89 \times 10^{-16}$   $\text{cm}^2/\text{s}$  and  $1.8 \times 10^{-16}$   $\text{cm}^2/\text{s}$ , respectively. It strongly manifests that the  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  possesses excellent electrical conductivity and high  $\text{Li}^+$  mobility, which can enhance lithium storage performance [51,52].

In summary, we have successfully fabricated  $\text{Sb}_2\text{Se}_3@\text{CNF}$ , via a novel electrospinning method, for utilization as anode materials within LIBs. The  $\text{Sb}_2\text{Se}_3@\text{CNF-600}$  delivered a remarkably high discharge capacity of 625 mA h/g after 100 cycles and 490 mAh/g after 500 cycles at current density of 100 mA/g and 1.0 A/g,

respectively. The N-doped carbon nanofibers contribute to the excellent electrochemical performance of the  $\text{Sb}_2\text{Se}_3$  due to its roles within the conductive matrix and its ability to act as a buffer layer, preventing the destructive volume expansion of  $\text{Sb}_2\text{Se}_3$ . Therefore,  $\text{Sb}_2\text{Se}_3/\text{CNF}-600$  can be regarded as a promising anode for LIBs in the future.

#### Declaration of competing interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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#### Appendix A. Supplementary data

Supplementary material related to this article can be found, in the online version, at doi:<https://doi.org/10.1016/j.ccllet.2019.11.039>.

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